## 1.8V Drive Nch+Nch MOSFET

### EM6K6

#### Structure

Silicon N-channel MOSFET

#### Applications

Switching

#### ●Features

- 1) The MOSFET elements are independent, eliminating mutual interference.
- 2) Mounting cost and area can be cut in half.
- 3) Low on-resistance.
- 4) Low voltage drive (1.8V) makes this device ideal for portable equipment.

#### Packaging specifications

Туре	Package	Taping
	Code	T2R
	Basic ordering unit (pieces)	8000
EM6K6		0

#### ● Absolute maximum ratings (Ta=25°C)

<It is the same ratings for the Tr1 and Tr2>

Parameter		Symbol	Limits	Unit
Drain-source voltage		VDSS	20	V
Gate-source voltage		Vgss	±8	V
Drain current	Continuous	lσ	±300	mA
	Pulsed	IDP *1	±600	mA
Total power dissipation		Pp*2	150	mW / TOTAL
		PD	120	mW / ELEMENT
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55 to +150	°C

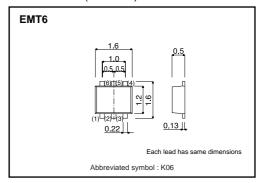
<sup>\*1</sup> Pw≤10μs, Duty cycle≤1%

#### ●Thermal resistance

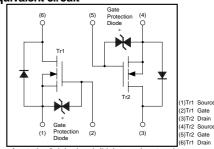
Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a)*	833	°C/W / TOTAL
Charmer to ambient	Kui(cii-a)	1042	°C/W / ELEMENT

<sup>\*</sup> Each terminal mounted on a recommended land

#### ●Dimensions (Unit: mm)



#### ●Equivalent circuit



(1) Protection (2) (3) (5)Tr2 Gate (6)Tr1 Drain

A protection diode has been built in between the gate and the source to protect against static electricity when the product is in use. Use the protection circuit when rated voltages are exceeded.

<sup>\*2</sup> Each terminal mounted on a recommended land.

#### ●Electrical characteristics (Ta=25°C)

<It is the same characteristics for the Tr1 and Tr2>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	Igss	-	-	±10	μΑ	Vgs=±8V, Vps=0V
Drain-source breakdown voltage	V(BR)DSS	20	-	-	V	In=1mA, Vgs=0V
Zero gate voltage drain current	IDSS	-	-	1.0	μΑ	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V
Gate threshold voltage	VGS(th)	0.3	_	1.0	V	VDS=10V, ID=1mA
Static drain-source on-state resistance		_	0.7	1.0	Ω	In=300mA, Vgs=4.0V
	RDS(on)*	_	0.8	1.2	Ω	In=300mA, Vgs=2.5V
		-	1.0	1.4	Ω	In=300mA, Vgs=1.8V
Forward transfer admittance	Yfs  *	400	_	-	ms	ID=300mA, VDS=10V
Input capacitance	Ciss	-	25	-	pF	V <sub>D</sub> S=10V
Output capacitance	Coss	_	10	_	pF	Vgs=0V
Reverse transfer capacitance	Crss	_	10	_	pF	f=1MHz
Turn-on delay time	td(on) *	_	5	_	ns	I <sub>D</sub> =150mA, V <sub>DD</sub> ≒10V
Rise time	tr *	_	10	_	ns	V <sub>G</sub> S=4.0V
Turn-off delay time	td(off) *	_	15	_	ns	RL=67Ω
Fall time	t <sub>f</sub> *	_	10	_	ns	R <sub>G</sub> =10Ω

<sup>\*</sup> Pulsed

#### ●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp*	_	_	1.2	V	I <sub>S</sub> = 100mA, V <sub>GS</sub> =0V

<sup>\*</sup> Pulsed

#### •Electrical characteristic curves

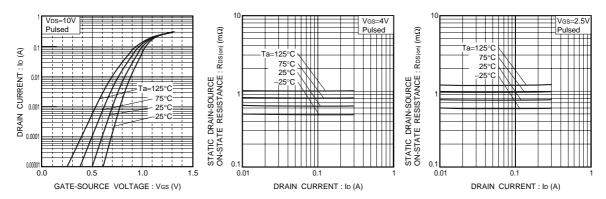


Fig.1 Typical transfer characteristics

Fig.2 Static drain-source on-state resistance vs. drain current (I)

Fig.3 Static drain-source on-state resistance vs. drain current (II)

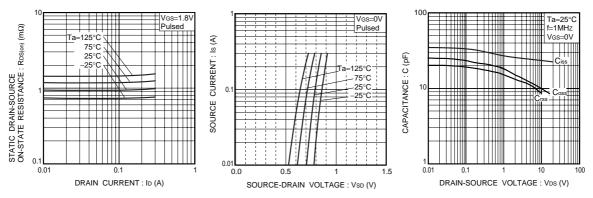


Fig.4 Static drain-source on-state resistance vs. drain current (III)

Fig.5 Source current vs. source-drain voltage

Fig.6 Typical capacitance vs. drain-source voltage

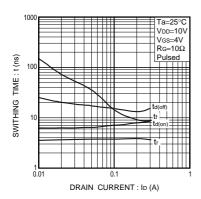


Fig.7 Switching characteristics

#### Switching characteristics measurement circuit

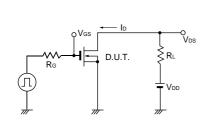


Fig.8 Switching time measurement circuit

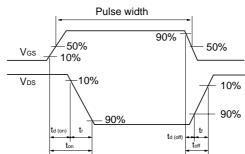


Fig.9 Switching time waveforms

#### Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any
  means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the
  product described in this document are for reference only. Upon actual use, therefore, please request
  that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard
  use and operation. Please pay careful attention to the peripheral conditions when designing circuits
  and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or
  otherwise dispose of the same, no express or implied right or license to practice or commercially
  exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

It is our top priority to supply products with the utmost quality and reliability. However, there is always a chance of failure due to unexpected factors. Therefore, please take into account the derating characteristics and allow for sufficient safety features, such as extra margin, anti-flammability, and fail-safe measures when designing in order to prevent possible accidents that may result in bodily harm or fire caused by component failure. ROHM cannot be held responsible for any damages arising from the use of the products under conditions out of the range of the specifications or due to non-compliance with the NOTES specified in this catalog.

Thank you for your accessing to ROHM product informations.

More detail product informations and catalogs are available, please contact your nearest sales office.

**ROHM** Customer Support System

THE AMERICAS / EUPOPE / ASIA / JAPAN

www.rohm.com

Contact us : webmaster@rohm.co.jp

Copyright © 2007 ROHM CO.,LTD.

ROHM CO., LTD. 21, Saiin Mizosaki-cho, Ukyo-ku, Kyoto 615-8585, Japan

oan TEL:+81-75-311-2121 FAX:+81-75-315-0172



# www.s-manuals.com